

	Class	Subclass
ISSUE CLASSIFICATION		

N

PATENT NUMBER

U.S. **UTILITY** Patent Application

O.I.P.E.

PATENT DATE

SCANNED

Q.A

APPLICATION NO. 09/917440	CONT/PRIOR	CLASS 257	SUBCLASS 296	ART UNIT 2811 2836	EXAMINER [Signature] Quinto
------------------------------	------------	--------------	-----------------	-------------------------------------	---

ICANTS Zhigang Wang
Nian Yang
Yue-Song He

APPLICANTS

Title

N-Gate/N-Substrate or P-Gate/P-Substrate Capacitor to Characterize polysilicon gate depletion evaluation

PTO-2040
12/89**ISSUING CLASSIFICATION**

ORIGINAL						CROSS REFERENCE(S)								
CLASS			SUBCLASS			CLASS	SUBCLASS (ONE SUBCLASS PER BLOCK)							
INTERNATIONAL CLASSIFICATION														
							<input type="checkbox"/> Continued on Issue Slip Inside File Jacket							

<input type="checkbox"/> TERMINAL DISCLAIMER	DRAWINGS		CLAIMS ALLOWED	
	Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims
<input type="checkbox"/> The term of this patent subsequent to _____ (date) has been disclaimed.	_____ (Assistant Examiner)		NOTICE OF ALLOWANCE MAILED _____	
<input type="checkbox"/> The term of this patent shall not extend beyond the expiration date of U.S Patent. No. _____ _____ _____	_____ (Primary Examiner) _____ (Date)		ISSUE FEE	
			Amount Due	Date Paid
____ The terminal ____ months of this patent have been disclaimed.	_____ (Legal Instruments Examiner) _____ (Date)		ISSUE BATCH NUMBER	
WARNING: The information disclosed herein may be restricted. Unauthorized disclosure may be prohibited by the United States Code Title 35, Sections 122, 181 and 368. Possession outside the U.S. Patent & Trademark Office is restricted to authorized employees and contractors only.				

Form **PTO-436A**
(Rev. 6/99)

FILED WITH: ☐ DISK (CRF) ☐ FICHE ☐ CD-ROM
(Attached in pocket on right inside flap)

(FACE)